

10A, 50V - 1000V High Efficient Rectifier

FEATURES

- AEC-Q101 qualified available
- High efficiency, low V_F
- High current capability
- High surge current capability
- Low power loss
- UL Recognized File # E-326243
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

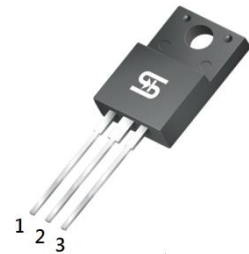
APPLICATIONS

- DC to DC converter
- Switching mode converters and inverters
- Freewheeling application

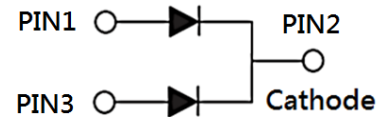
MECHANICAL DATA

- Case: ITO-220AB
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Mounting torque: 0.56 N·m maximum
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 1.82g (approximately)

KEY PARAMETERS		
PARAMETER	VALUE	UNIT
I_F	10	A
V_{RRM}	50 - 1000	V
I_{FSM}	125	A
$T_{J\ MAX}$	150	°C
Package	ITO-220AB	
Configuration	Dual dies	



ITO-220AB



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)										
PARAMETER	SYMBOL	HERF 1001G	HERF 1002G	HERF 1003G	HERF 1004G	HERF 1005G	HERF 1006G	HERF 1007G	HERF 1008G	UNIT
Marking code on the device		HERF 1001G	HERF 1002G	HERF 1003G	HERF 1004G	HERF 1005G	HERF 1006G	HERF 1007G	HERF 1008G	
Repetitive peak reverse voltage	V_{RRM}	50	100	200	300	400	600	800	1000	V
Reverse voltage, total rms value	$V_{R(RMS)}$	35	70	140	210	280	420	560	700	V
Forward current	I_F	10								A
Surge peak forward current, 8.3ms single half sine wave superimposed on rated load	I_{FSM}	125								A
Junction temperature	T_J	-55 to +150								°C
Storage temperature	T_{STG}	-55 to +150								°C

THERMAL PERFORMANCE

PARAMETER	SYMBOL	TYP	UNIT
Junction-to-case thermal resistance	$R_{\theta JC}$	3	°C/W

ELECTRICAL SPECIFICATIONS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

PARAMETER	CONDITIONS	SYMBOL	TYP	MAX	UNIT
Forward voltage per diode ⁽¹⁾	HERF1001G	V_F	-	1.0	V
	HERF1002G				
	HERF1003G		-	1.3	V
	HERF1004G				
	HERF1005G				
	HERF1006G		-	1.7	V
	HERF1007G				
Reverse current @ rated V_R per diode ⁽²⁾	$T_J = 25^\circ\text{C}$	I_R	-	10	μA
	$T_J = 125^\circ\text{C}$		-	400	μA
Junction capacitance per diode	HERF1001G	1MHz, $V_R = 4.0\text{V}$	60	-	pF
	HERF1002G				
	HERF1003G				
	HERF1004G				
	HERF1005G		40	-	pF
	HERF1006G				
	HERF1007G				
Reverse recovery time	HERF1001G	$I_F = 0.5\text{A}$, $I_R = 1.0\text{A}$ $I_{rr} = 0.25\text{A}$	-	50	ns
	HERF1002G				
	HERF1003G				
	HERF1004G				
	HERF1005G		-	80	ns
	HERF1006G				
	HERF1007G				
	HERF1008G				

Notes:

1. Pulse test with $PW = 0.3\text{ms}$
2. Pulse test with $PW = 30\text{ms}$

ORDERING INFORMATION

ORDERING CODE ⁽¹⁾⁽²⁾	PACKAGE	PACKING
HERF10xG	ITO-220AB	50 / Tube
HERF10xGH	ITO-220AB	50 / Tube

Notes:

1. "x" defines voltage from 50V(HERF1001G) to 1000V(HERF1008G)
2. "H" means AEC-Q101 qualified

CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)

Fig.1 Forward Current Derating Curve

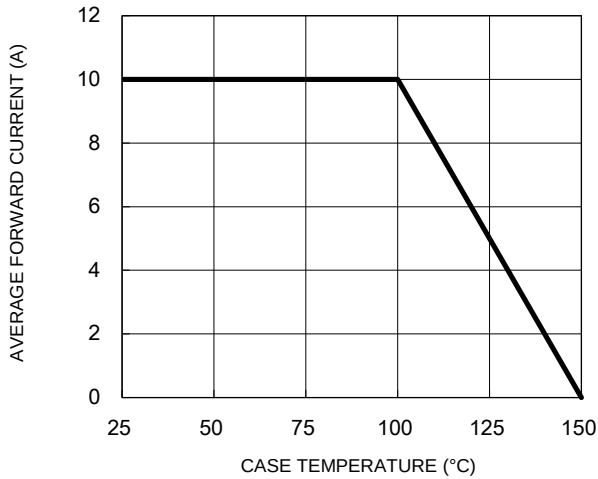


Fig.2 Typical Junction Capacitance

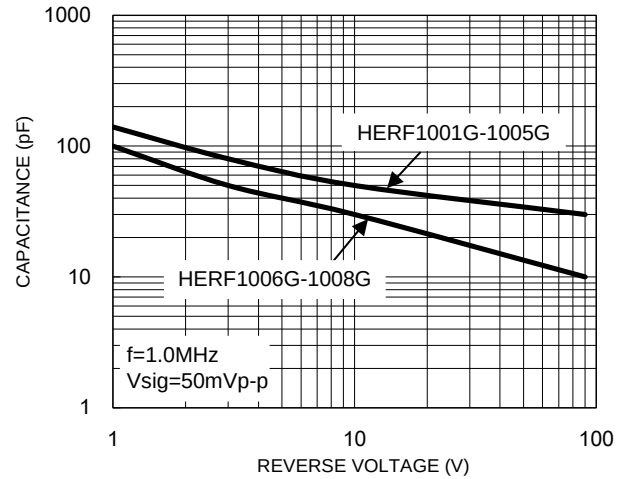


Fig.3 Typical Reverse Characteristics

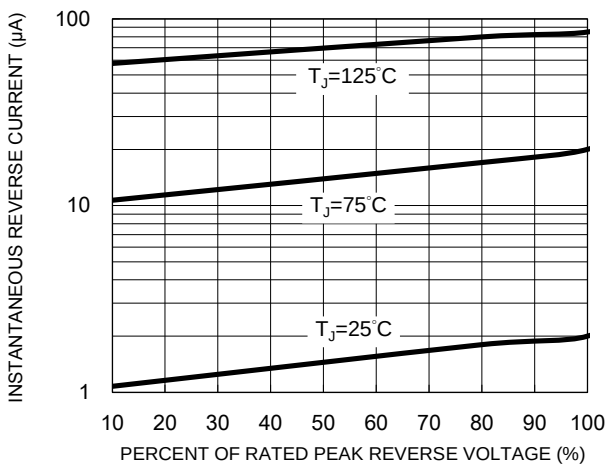


Fig.4 Typical Forward Characteristics

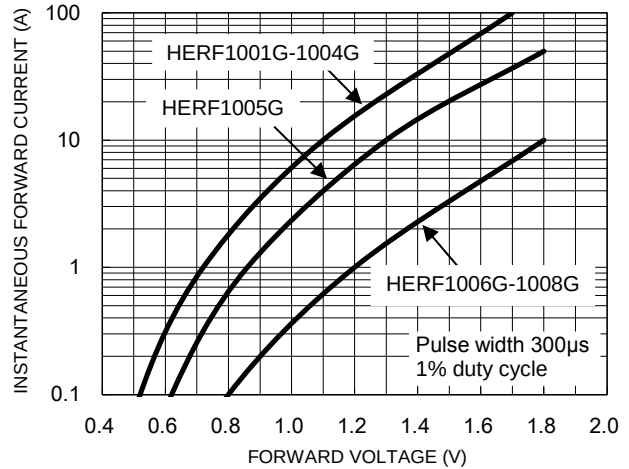
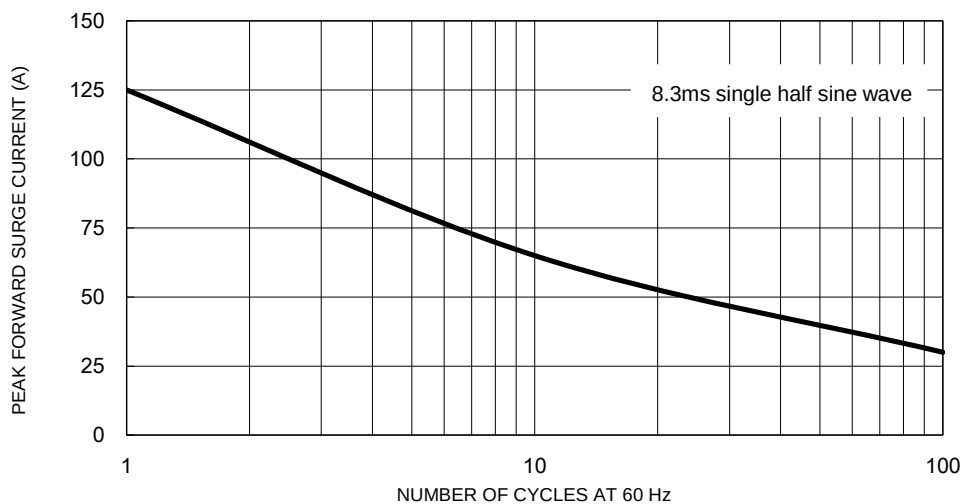


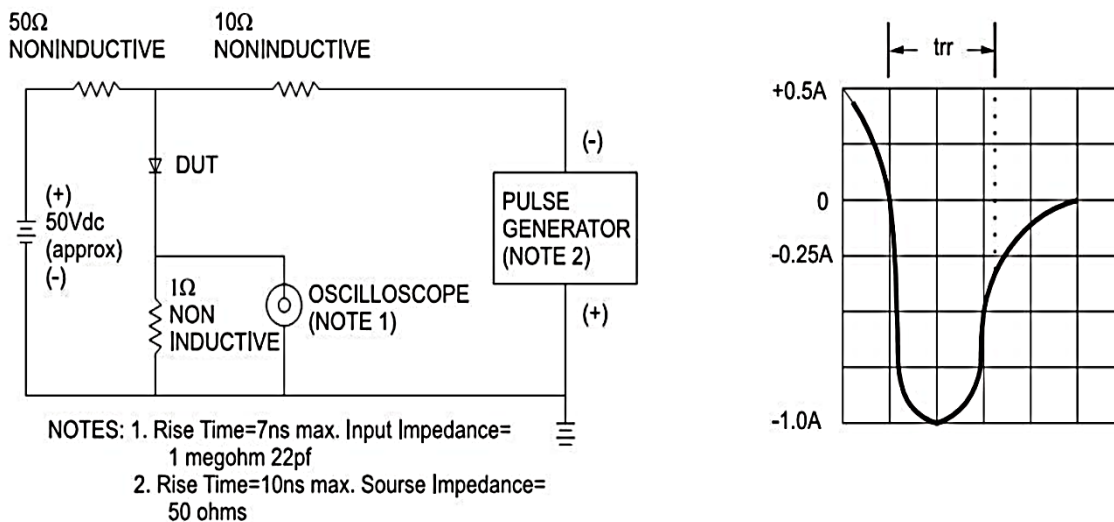
Fig.5 Maximum Non-Repetitive Forward Surge Current



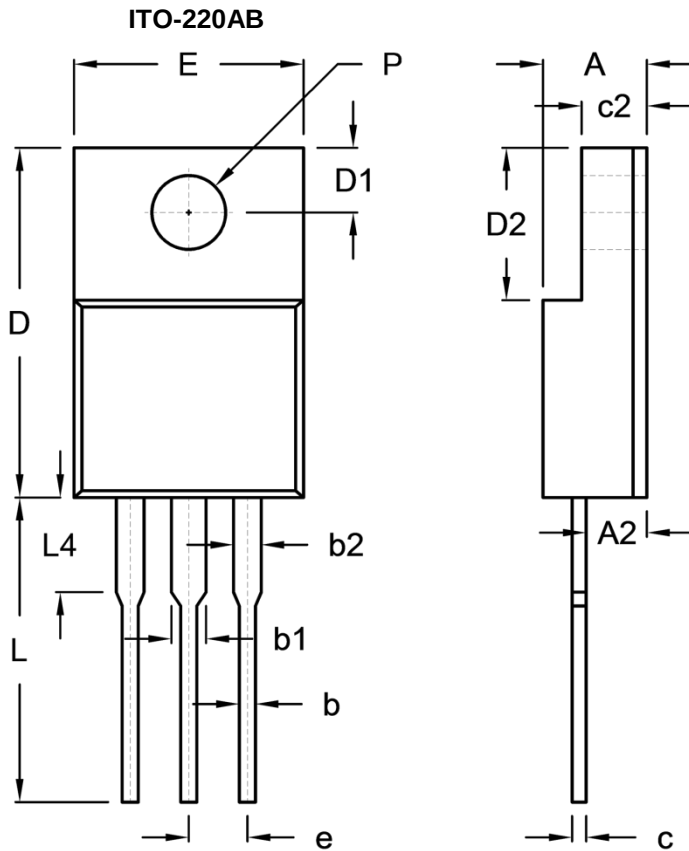
CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)

Fig.6 Reverse Recovery Time Characteristic and Test Circuit Diagram



PACKAGE OUTLINE DIMENSIONS



DIM.	Unit (mm)		Unit (inch)	
	Min.	Max.	Min.	Max.
A	4.30	4.70	0.169	0.185
A2	2.30	2.96	0.091	0.117
b	0.50	0.90	0.020	0.035
b1	-	1.80	-	0.071
b2	0.95	1.45	0.037	0.057
c	0.46	0.76	0.018	0.030
c2	2.50	3.16	0.098	0.124
D	14.80	15.50	0.583	0.610
D1	2.40	3.20	0.094	0.126
D2	6.30	6.90	0.248	0.272
E	9.60	10.30	0.378	0.406
e	2.41	2.67	0.095	0.105
L	12.60	13.80	0.496	0.543
L4	-	4.10	-	0.161
P	3.00	3.40	0.118	0.134

MARKING DIAGRAM



P/N = Marking Code
 G = Green Compound
 YWW = Date Code
 F = Factory Code

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